General Purpose Transistors

PNP Silicon

Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V _{CEO}	-65 -45 -30	V
Collector-Base Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V _{CBO}	80 50 30	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current – Continuous	Ι _C	-100	mAdc
Collector Current – Peak	Ι _C	-200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta J A}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

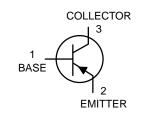
1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



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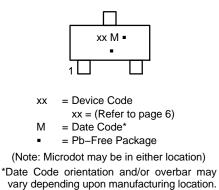
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SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



ORDERING INFORMATION

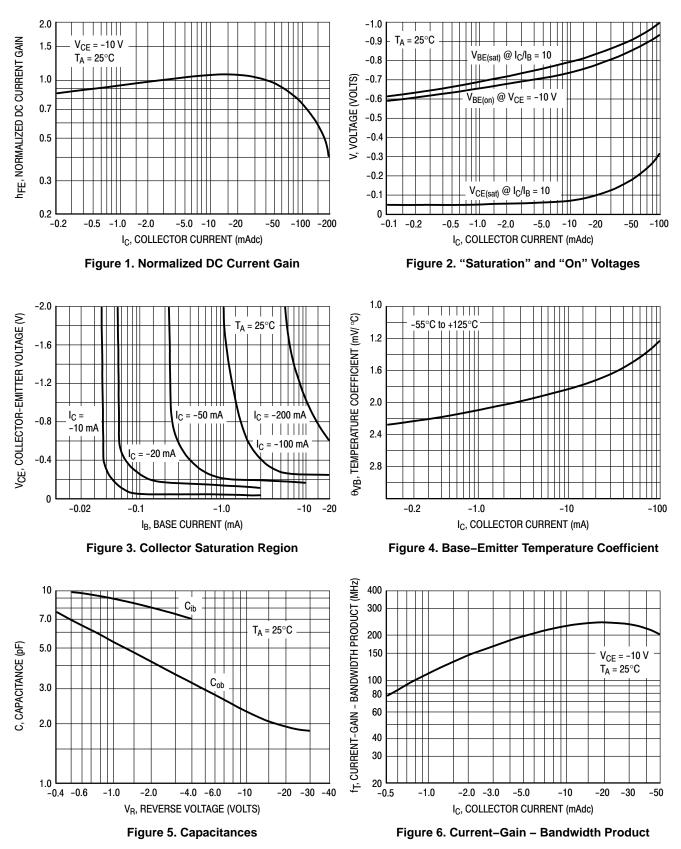
See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

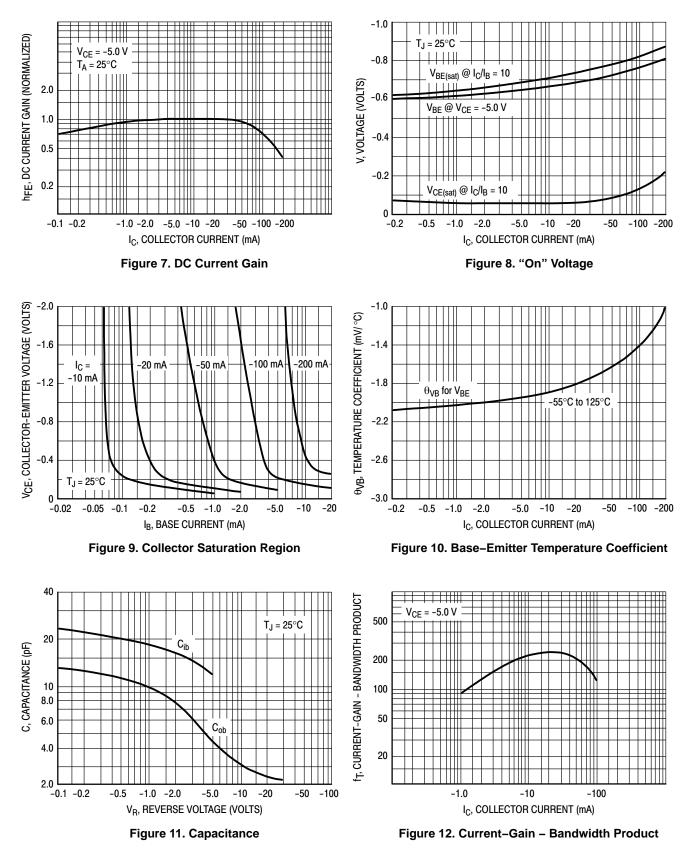
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown VoltageBC856, SBC856 Series(I _C = -10 mA)BC857, SBC857 SeriesBC858, NSBVC858 BC859 Series	V _{(BR)CEO}	-65 -45 -30	- - -	- - -	V
	V _{(BR)CES}	80 50 30	- - -	- - -	V
	V _{(BR)CBO}	80 50 30	- - -	- - -	V
$ \begin{array}{ll} \mbox{Emitter}-\mbox{Base Breakdown Voltage} & \mbox{BC856, SBC856 Series} \\ (I_E = -1.0 \ \mu A) & \mbox{BC857, SBC857 Series} \\ \mbox{BC858, NSVBC858, BC859 Series} \end{array} $	V _{(BR)EBO}	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current (V _{CB} = -30 V) (V _{CB} = -30 V, T _A = 150° C)	I _{CBO}	_ _	_ _	-15 -4.0	nA μA
DN CHARACTERISTICS					
DC Current Gain BC856A, SBC856A, BC857A, SBC857A, BC858A $(I_C = -10 \ \mu A, V_{CE} = -5.0 \ V)$ BC856B, SBC856B, BC857B, BC857B, BC858B, NSVBC858B	h _{FE}		90 150		-
BC857C, SBC857C BC858C		-	270	-	
$ (I_C = -2.0 \text{ mA}, \text{ V}_{CE} = -5.0 \text{ V}) \\ BC856A, \text{ SBC856A}, \text{ BC857A}, \\ SBC857A, \text{ BC858A} \\ BC856B, \text{ SBC856B}, \text{ BC857B}, \text{ SBC857B}, \text{ BC858B}, \\ BC856B, \text{ SBC856B}, \text{ BC857B}, \text{ SBC857B}, \text{ BC858B}, \\ BC856B, \text{ SBC856B}, \text{ BC857B}, \text{ SBC857B}, \text{ BC858B}, \\ BC856B, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ BC858B}, \\ BC856B, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ BC858B}, \\ BC856B, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \\ BC856B, \text{ SBC856B}, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \\ BC856B, \text{ SBC856B}, \text{ SBC856B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \text{ SBC857B}, \\ BC856B, \text{ SBC856B}, \text{ SBC856B}, \text{ SBC857B}, S$		125 220	180 290	250 475	
NSVBC858B, BC859B BC857C, SBC857C, BC858C, BC859C		420	520	800	
Collector – Emitter Saturation Voltage $(I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA})$ $(I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA})$	V _{CE(sat)}			-0.3 -0.65	V
Base – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$) ($I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$)	V _{BE(sat)}		-0.7 -0.9		V
Base – Emitter On Voltage ($I_C = -2.0 \text{ mA}$, $V_{CE} = -5.0 \text{ V}$) ($I_C = -10 \text{ mA}$, $V_{CE} = -5.0 \text{ V}$)	V _{BE(on)}	-0.6 -		-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product ($I_C = -10$ mA, $V_{CE} = -5.0$ Vdc, f = 100 MHz)	f _T	100	_	_	MHz
Output Capacitance ($V_{CB} = -10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$)	C _{ob}	-	-	4.5	pF
Noise Figure (I _C = -0.2 mA, V _{CE} = -5.0 Vdc, R _S = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz) BC856, SBC856, BC857, SBC857, BC858, NSVBC858 Series BC859 Series	NF			10 4.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

BC857/BC858/BC859/SBC857/NSVBC858



BC856/SBC856



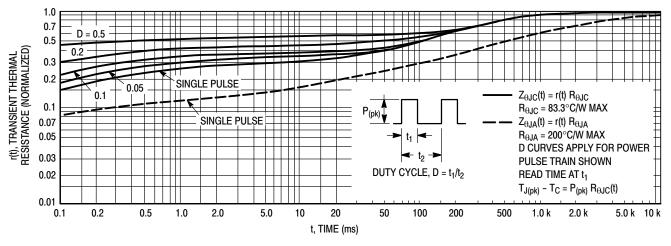


Figure 13. Thermal Response

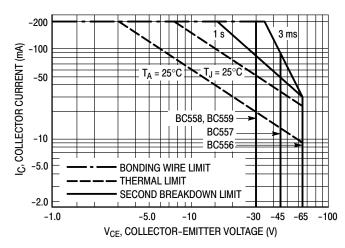


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150^{\circ}C$; T_C or T_A is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

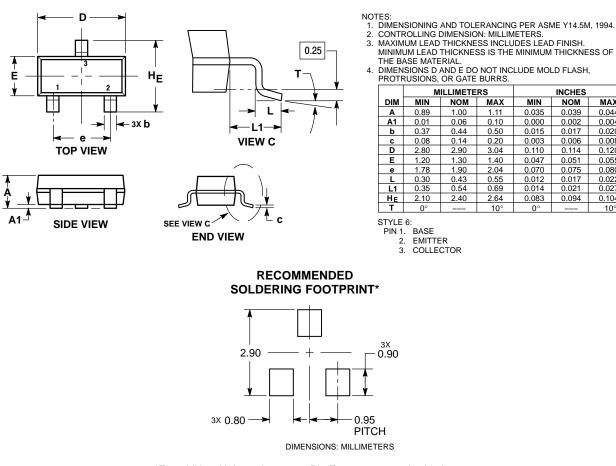
ORDERING INFORMATION

Device	Marking	Package	Shipping †		
BC856ALT1G	3A	SOT-23	3,000 / Tape & Reel		
SBC856ALT1G*		(Pb-Free)			
BC856ALT3G			10,000 / Tape & Reel		
BC856BLT1G	3B	SOT-23	3,000 / Tape & Reel		
SBC856BLT1G*		(Pb-Free)			
BC856BLT3G			10,000 / Tape & Reel		
SBC856BLT3G*					
BC857ALT1G	3E	SOT-23	3,000 / Tape & Reel		
SBC857ALT1G*		(Pb-Free)			
BC857BLT1G	3F	SOT-23	3,000 / Tape & Reel		
SBC857BLT1G*		(Pb-Free)			
BC857BLT3G			10,000 / Tape & Reel		
NSVBC857BLT3G*					
BC857CLT1G	3G SOT-23 (Pb-Free)		3,000 / Tape & Reel		
SBC857CLT1G*		(Pb-Free)			
BC857CLT3G			10,000 / Tape & Reel		
BC858ALT1G	3J	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC858BLT1G	ЗК	SOT-23			
NSVBC858BLT1G*		(Pb-Free)			
BC858BLT3G	3L	SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC858CLT1G		SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC858CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC859BLT1G	4B	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC859BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC859CLT1G	4C	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC859CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR**



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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